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View Online at https://aerobasegroup.com/nsn/5961-01-128-9133 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.293 inches and 0.357 inches **Terminal Length:** Between 1.000 inches and 1.625 inches **Overall Diameter:** Between 0.150 inches and 0.185 inches **Function For Which Designed:** Transient suppressor **End Application:** Stores mgmt 76301 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-13 Electrode Internally-electrically Connected To Case: Cathode **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.5 reverse voltage, dc **Current Rating Per Characteristic:** 200.00 amperes forward current, average preset **Power Rating Per Characteristic:** 1500.0 watts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/434 government specification Shelf Life: N/a Unit Of Measure: **Demilitarization:**

No

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